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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/741,670	12/18/2003	Sang-Hyun Oh	51876P456	4170
8791 7	7590 10/20/2004		EXAMINER	
BLAKELY SOKOLOFF TAYLOR & ZAFMAN			KESHAVAN, BELUR V	
12400 WILSH SEVENTH FL	IRE BOULEVARD		ART UNIT	PAPER NUMBER
	ES, CA 90025-1030		2825	

DATE MAILED: 10/20/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)				
Office Action Summary		10/741,670	OH ET AL.				
		Examiner	Art Unit ,	·			
		Belur V Keshavan	2825	_			
Period f	The MAILING DATE of this communication aport Reply	ppears on the cover sheet w	th the correspondence address				
THE - Extended - If th - If NO - Fail Any	HORTENED STATUTORY PERIOD FOR REP MAILING DATE OF THIS COMMUNICATION ensions of time may be available under the provisions of 37 CFR 1 r SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a re o period for reply is specified above, the maximum statutory period ure to reply within the set or extended period for reply will, by statu- reply received by the Office later than three months after the mail- ned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a r ply within the statutory minimum of third d will apply and will expire SIX (6) MON te, cause the application to become AE	eply be timely filed  y (30) days will be considered timely.  THS from the mailing date of this communication.  ANDONED (35 U.S.C. § 133).				
Status							
1)🖂	Responsive to communication(s) filed on 01	October 2004.					
2a)⊠	☐ This action is <b>FINAL</b> . 2b)☐ This action is non-final.						
3)	3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposit	tion of Claims		·				
4)🖂	Claim(s) 1-7 is/are pending in the application						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)[	Claim(s) is/are allowed.						
6)⊠	Claim(s) <u>1 and 4</u> is/are rejected.						
7)							
8)□	Claim(s) are subject to restriction and/or election requirement.						
Applicat	ion Papers						
9)[	The specification is objected to by the Examir	ner.					
10)	The drawing(s) filed on is/are: a) ac	cepted or b) objected to	by the Examiner.				
	Applicant may not request that any objection to the	e drawing(s) be held in abeyar	ce. See 37 CFR 1.85(a).				
	Replacement drawing sheet(s) including the corre	ction is required if the drawing	s) is objected to. See 37 CFR 1.121(d).				
11)	The oath or declaration is objected to by the E	Examiner. Note the attached	Office Action or form PTO-152.				
Priority	under 35 U.S.C. § 119						
а)	Acknowledgment is made of a claim for foreig  All b) Some * c) None of:  1. Certified copies of the priority documer  2. Certified copies of the priority documer  3. Copies of the certified copies of the priority documer  application from the International Burea  See the attached detailed Office action for a list	nts have been received.  Its have been received in A ority documents have been au (PCT Rule 17.2(a)).	pplication No received in this National Stage				
Attachmen							
	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948)		ummary (PTO-413) )/Mail Date				
	e of Draπsperson's Patent Drawing Review (P10-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08		formal Patent Application (PTO-152)				
	er No(s)/Mail Date	6) 🔲 Other:					

### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 1 is rejected under 35 U.S.C. 102(b) as being anticipated by applicant's admitted prior art, hereinafter APA, as shown in figure 3C.

Regarding claim 1, APA discloses a method for fabricating a ferroelectric random access memory device, comprising the steps of:

Forming a first inter-layer insulation layer (24) on a substrate (21); forming a storage node contact (25) connected with a partial portion of the substrate by passing through the first inter-layer insulation layer; forming a lower electrode (29) connected to the storage node contact on the first inter-layer insulation layer; forming a second inter-layer insulation layer (26) having a surface level lower than that of the lower electrode so that the second inter-layer insulation layer encompasses a bottom part of the lower electrode; forming an impurity diffusion barrier layer (27) encompassing sidewalls of an upper part of the lower electrode on the second interlayer insulation layer; forming a ferroelectric layer (30) on the lower electrode and diffusion barrier layer; and forming a top electrode (31) on the ferroelectric layer.

## Allowable Subject Matter

Claims 2, 3, 4 5, 6 and 7 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Remarks

Applicant's arguments in Remarks filed on October 1, 2004 have been fully considered but they are not persuasive.

The examiner has noted the amendment to claim1.

The examiner notes the applicant's argument that the applicant's claimed invention asserts, after the amendment to claim 1, a step of forming a second interlayer insulation layer having a surface level lower than that of the lower electrode so that the second interlayer insulation layer encompasses a bottom part of the lower electrode and further, the impurity diffusion barrier layer of applicant's claimed invention encompasses the side walls of an upper part of the lower electrode on the second interlayer insulation layer. APA does not disclose, teach or suggest all of applicant's amended claim 1 limitations and accordingly the applicant request the withdrawal of the 35 U.S.C 102(b) rejections of claims 1 and 4. However, the examiner is not persuaded by the applicant's arguments because as stated above, APA does anticipate claim 1. As shown in figure 3C, APA discloses a method for fabricating a ferroelectric random access memory device, comprising the steps of: forming a second inter-layer insulation layer (26) having a surface level lower than that of the lower electrode so that the second interlayer insulation layer encompasses a bottom part of the lower electrode; forming an impurity

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diffusion barrier layer (27) encompassing sidewalls of an upper part of the lower electrode on the second inter-layer insulation layer.

#### Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

## **Contact Information**

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Belur V Keshavan whose telephone number is 571-272-1894. The examiner can normally be reached on 8-4:30 Monday to Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S Smith can be reached on 571-272-1907. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

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system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

BVK. WAR October 14, 2004.

Belur V. Keshavan. Examiner. Art Unit 2825. Page 5

MATTHEW SMITH SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800